

NL17SV00

Single 2-Input NAND Gate

The NL17SV00 is an ultra-high performance 2-Input NAND gate manufactured in 0.35 μm technology, with excellent performance down to 0.9 V. This device is ideal for extremely high speed and high-drive applications. Additionally, limitations of board space are no longer a constraint. The very small SOT-553 makes this device fit most tight designs and spaces.

Features

- Extremely High Speed: 1.0 ns (Typ) @ $V_{CC} = 3.3\text{ V}$
- Designed for 0.9 to 3.3 V Operation
- Overvoltage Tolerance (OVT)* Input Pins Permits Logic Translation
- Balanced $\pm 24\text{ mA}$ Output Drive @ $V_{CC} 3.3\text{ V}$
- Near Zero Static Supply Current
- Ultra-Tiny SOT-553 5-Pin Package, only 1.6 x 1.6 x 0.6 mm
- These Devices are Pb-Free and are RoHS Compliant

Typical Applications

- Cellular
- Digital Camera
- PDA
- Digital Video

Industry Leadership

- Functionally Similar to NC7SV00 and SN74AUC1G00

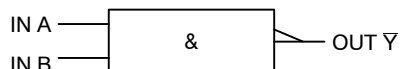


Figure 1. Logic Symbol

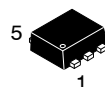
FUNCTION TABLE

Inputs		Output
A	B	$\bar{Y}$
L	L	H
L	H	H
H	L	H
H	H	L



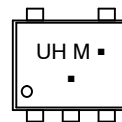
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SOT-553
CASE 463B

MARKING DIAGRAM



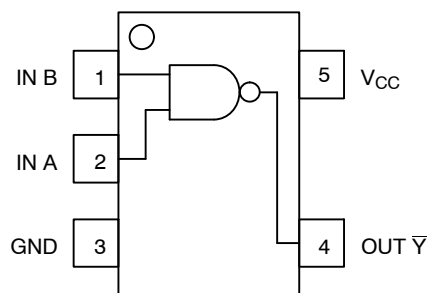
UH = Specific Device Code

M = Date Code

▪ = Pb-Free Package

(Note: Microdot may be in either location)

PIN DIAGRAM



PIN ASSIGNMENT

PIN #	FUNCTION
1	IN B
2	IN A
3	GND
4	OUT $\bar{Y}$
5	V_{CC}

ORDERING INFORMATION

Device	Package	Shipping†
NL17SV00XV5T2G	SOT-553 (Pb-Free)	4000 Tape & Reel (178 mm)

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

*Overvoltage Tolerance (OVT) enables input pins to function outside (higher) of their operating voltages, with no damage to the devices or to signal integrity.

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MAXIMUM RATINGS

Symbol	Rating	Value	Units
V _{CC}	DC Supply Voltage	–0.5 to +4.6	V
V _I	DC Input Voltage	–0.5 to +4.6	V
V _O	DC Output Voltage	–0.5 to V _{CC} + 0.5	V
I _{IK}	DC Input Diode Current V _{IN} < 0 V	–50	mA
I _{OK}	DC Output Diode Current V _{OUT} < 0 V V _{OUT} > V _{CC}	–50 +50	mA
I _O	DC Output Sink Current	±50	mA
I _{CC}	DC Supply Current per Supply Pin	±50	mA
I _{GND}	DC Ground Current per Ground Pin	±50	mA
T _{STG}	Storage Temperature Range	– 65 to +150	°C
T _L	Lead Temperature, 1.0 mm from Case for 10 seconds	260	°C
T _J	Junction Temperature Under Bias	+150	°C
θ _{JA}	Thermal Resistance (Note 1)	250	°C/W
P _D	Power Dissipation in Still Air at 85°C	250	mW
MSL	Moisture Sensitivity	Level 1	
F _R	Flammability Rating Oxygen index: 28 to 34	UL 94 V–0 @ 0125 in	

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

1. Measured with minimum pad spacing on an FR4 board, using 10 mm–by–1 inch, 2 ounce copper trace no air flow.
2. Tested to EIA/JESD22–A114–A.
3. Tested to EIA/JESD22–A115–A.

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Min	Max	Units
V _{CC}	Positive DC Supply Voltage	0.9	3.6	V
V _{IN}	Digital Input Voltage	0	3.6	V
V _{out}	Output Voltage	0	V _{CC}	V
I _{OH} /I _{OL}	Output Current V _{CC} = 3.0 V to 3.6 V V _{CC} = 2.3 V to 2.7 V V _{CC} = 1.65 V to 1.95 V V _{CC} = 1.4 V to 1.6 V V _{CC} = 1.1 V to 1.3 V V _{CC} = 0.9 V		±24 ±18 ±6 ±4 ±2 ±0.1	mA
t _A	Operating Temperature Range. All Package Types	–40	+85	°C
t _r , t _f	Input Rise or Fall Time V _{CC} = 3.3V ± 0.3 V	0	10	nS/V

DEVICE JUNCTION TEMPERATURE VERSUS TIME TO 0.1% BOND FAILURES

Junction, Temperature °C	Time, Hours	Time, Years
80	1,032,200	117.8
90	419,300	47.9
100	178,700	20.4
110	79,600	9.4
120	37,000	4.2
130	17,800	2.0
140	8,900	1.0

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DC CHARACTERISTICS— Digital Section (Voltages Referenced to GND)

Symbol	Parameter	Condition	V _{CC}	T _A = 25°C		T _A = -40 to 85°C		Units
				Min	Max	Min	Max	
V _{IH}	High Level Input Voltage		0.90 1.10 ≤ V _{CC} ≤ 1.30 1.40 ≤ V _{CC} ≤ 1.60 1.65 ≤ V _{CC} ≤ 1.95 2.30 ≤ V _{CC} ≤ 2.70 2.70 ≤ V _{CC} ≤ 3.60	0.65 × V _{CC} 0.65 × V _{CC} 0.65 × V _{CC} 0.65 × V _{CC} 1.6 2.0		0.65 × V _{CC} 0.65 × V _{CC} 0.65 × V _{CC} 0.65 × V _{CC} 1.6 2.0		V
V _{IL}	Low Level Input Voltage		0.90 1.10 ≤ V _{CC} ≤ 1.30 1.40 ≤ V _{CC} ≤ 1.60 1.65 ≤ V _{CC} ≤ 1.95 2.30 ≤ V _{CC} ≤ 2.70 2.70 ≤ V _{CC} ≤ 3.60		0.35 × V _{CC} 0.35 × V _{CC} 0.35 × V _{CC} 0.35 × V _{CC} 0.7 0.8		0.35 × V _{CC} 0.35 × V _{CC} 0.35 × V _{CC} 0.35 × V _{CC} 0.7 0.8	V
V _{OH}	High Level Output Voltage	I _{OH} = -100 μA	0.90 1.10 ≤ V _{CC} ≤ 1.30 1.40 ≤ V _{CC} ≤ 1.60 1.65 ≤ V _{CC} ≤ 1.95 2.30 ≤ V _{CC} ≤ 2.70 2.70 ≤ V _{CC} ≤ 3.60	V _{CC} - 0.1 V _{CC} - 0.1 V _{CC} - 0.2 V _{CC} - 0.2 V _{CC} - 0.2 V _{CC} - 0.2		V _{CC} - 0.1 V _{CC} - 0.1 V _{CC} - 0.2 V _{CC} - 0.2 V _{CC} - 0.2 V _{CC} - 0.2		V
		I _{OH} = -2.0 mA	1.10 ≤ V _{CC} ≤ 1.30	0.75 × V _{CC}		0.75 × V _{CC}		
		I _{OH} = -4.0 mA	1.40 ≤ V _{CC} ≤ 1.60	0.75 × V _{CC}		0.75 × V _{CC}		
		I _{OH} = -6.0 mA	1.65 ≤ V _{CC} ≤ 1.95 2.30 ≤ V _{CC} ≤ 2.70	1.25 2.0		1.25 2.0		
		I _{OH} = -12 mA	2.30 ≤ V _{CC} ≤ 2.70 2.70 ≤ V _{CC} ≤ 3.60	1.8 2.2		1.8 2.2		
		I _{OH} = -18 mA	2.30 ≤ V _{CC} ≤ 2.70 2.70 ≤ V _{CC} ≤ 3.60	1.7 2.4		1.7 2.4		
		I _{OH} = -24 mA	2.70 ≤ V _{CC} ≤ 3.60	2.2		2.2		
V _{OL}	Low Level Output Voltage	I _{OL} = 100 μA	0.90 1.10 ≤ V _{CC} ≤ 1.30 1.40 ≤ V _{CC} ≤ 1.60 1.65 ≤ V _{CC} ≤ 1.95 2.30 ≤ V _{CC} ≤ 2.70 2.70 ≤ V _{CC} ≤ 3.60		0.1 0.1 0.2 0.2 0.2 0.2		0.1 0.1 0.2 0.2 0.2 0.2	V
		I _{OL} = 2.0 mA	1.10 ≤ V _{CC} ≤ 1.30		0.25 × V _{CC}		0.25 × V _{CC}	
		I _{OL} = 4.0 mA	1.40 ≤ V _{CC} ≤ 1.60		0.25 × V _{CC}		0.25 × V _{CC}	
		I _{OL} = 6.0 mA	1.65 ≤ V _{CC} ≤ 1.95		0.3		0.3	
		I _{OL} = 12 mA	2.30 ≤ V _{CC} ≤ 2.70 2.70 ≤ V _{CC} ≤ 3.60		0.4 0.4		0.4 0.4	
		I _{OL} = 18 mA	2.30 ≤ V _{CC} ≤ 2.70 2.70 ≤ V _{CC} ≤ 3.60		0.6 0.4		0.6 0.4	
		I _{OL} = 24 mA	2.70 ≤ V _{CC} ≤ 3.60		0.55		0.55	
I _{IN}	Input Leakage Current	0 = V _I = 3.6 V	0.90 to 3.60		±0.1		±0.9	μA
I _{OFF}	Power Off Leakage Current		0		1		5	μA
I _{CC}	Quiescent Supply Current	V _I = V _{CC} or GND	0.90 to 3.60		0.9		5	μA

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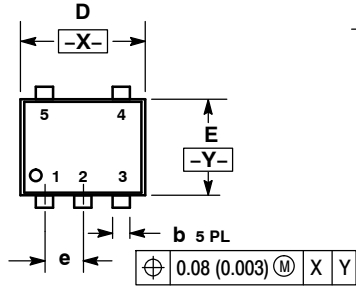
AC CHARACTERISTICS (Input $t_r = t_f = 3.0$ nS)

Symbol	Parameter	-40°C		25°C			85°C		Units
		Condition	V _{CC}	Min	Typ	Max	Min	Max	
T _{PHL} , T _{PLH}	Propagation Delay	C _L = 15 pF, R _L = 1.0 MΩ	0.90		13				nS
		C _L = 15 pF, R _L = 2.0 kΩ	1.10 ≤ V _{CC} ≤ 1.30 1.40 ≤ V _{CC} ≤ 1.60	3.0 1.0	6.0 3.2	9.9 6.0	1.0 1.0	14.6 7.2	nS
		C _L = 30 pF, R _L = 500 Ω	1.65 ≤ V _{CC} ≤ 1.95 2.30 ≤ V _{CC} ≤ 2.70 2.70 ≤ V _{CC} ≤ 3.60	1.0 0.8 0.7	1.9 1.2 1.0	4.5 2.6 2.3	1.0 0.7 0.6	5.3 3.7 3.0	nS
C _{IN}	Input Capacitance		0		2.0				pF
C _{OUT}	Output Capacitance		0		4.5				pF
C _{PD}	Power Dissipation Capacitance	V _I = 0 V or V _{CC} F = 10 MHz	0.90 to 3.60		20				pF

NL17SV00

PACKAGE DIMENSIONS

SOT-553, 5 LEAD CASE 463B-01 ISSUE B

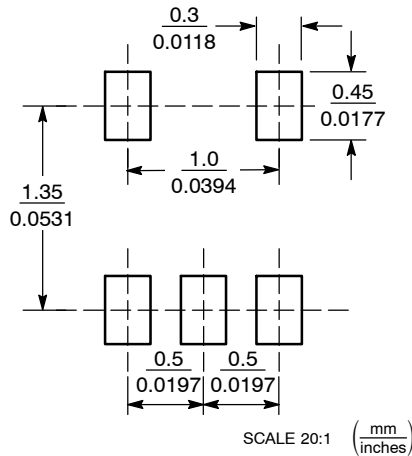


NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETERS
3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.

DIM	MILLIMETERS			INCHES		
	MIN	NOM	MAX	MIN	NOM	MAX
A	0.50	0.55	0.60	0.020	0.022	0.024
b	0.17	0.22	0.27	0.007	0.009	0.011
c	0.08	0.13	0.18	0.003	0.005	0.007
D	1.50	1.60	1.70	0.059	0.063	0.067
E	1.10	1.20	1.30	0.043	0.047	0.051
e	0.50 BSC			0.020 BSC		
L	0.10	0.20	0.30	0.004	0.008	0.012
HE	1.50	1.60	1.70	0.059	0.063	0.067

SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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